Ordering number: EN5541A

NPN Epitaxial Planar Silicon Transistor



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2SC5375

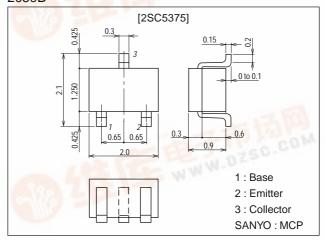
VHF to UHF Band OSC, High-Frequency Amplifiers Applications

Features

· High gain : | S21e | ²=10dB typ (f=1GHz). · High cutoff frequency : f_T=5.2GHz typ.

Package Dimensions

unit:mm 2059B



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Cymphal	Conditions	Datings	Unit
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		20	V
Collector-to-Emitter Voltage	V _{CEO}		10	V
Emitter-to-Base Voltage	V _{EBO}	pul.	2	V
Collector Current	Ic	no th	100	mA
Collector Dissipation	PC	- A.D. (1900 14)	150	mW
Junction Temperature	Tj	AND PARTIES A	150	°C
Storage Temperature	Tstg		-55 to +150	°C

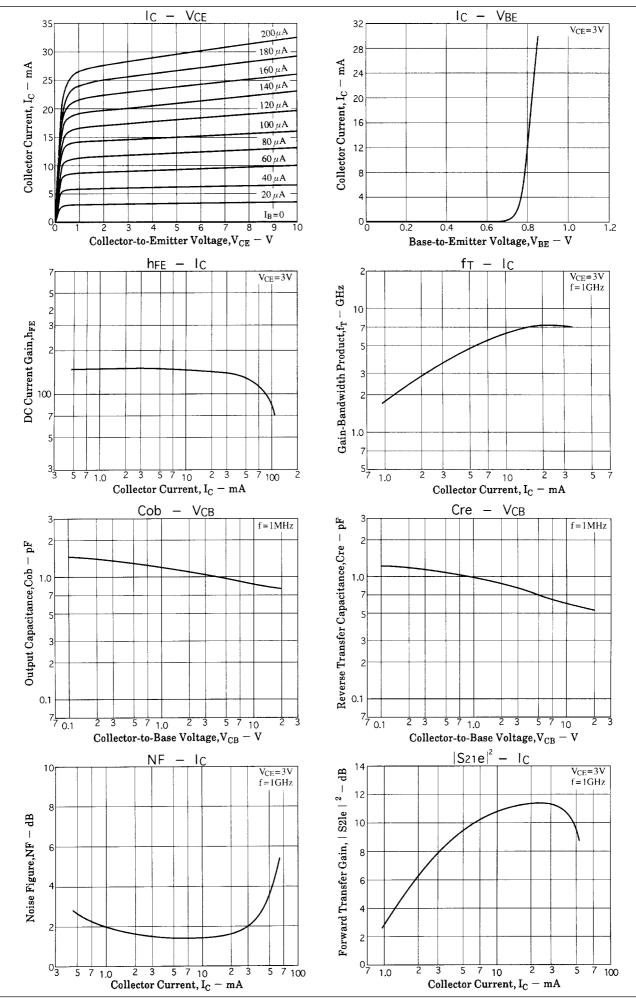
Electrical Characteristics at Ta = 25°C

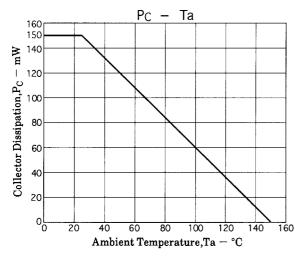
Parameter	Symbol	Conditions	Ratings			Unit
Falametei	Symbol	Conditions	min	typ	max	Oilit
Collector Cutoff Current	I _{CBO}	V _{CB} =10V, I _E =0			1.0	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =1V, I _C =0			10	μΑ
DC Current Gain	h _{FE} 1	V _{CE} =3V, I _C =7mA	110		180	
De Current Gairi	h _{FE} 2	V _{CE} =3V, I _C =30mA	100			
Gain-Bandwidth Product	fT	V _{CE} =3V, I _C =7mA	3	5.2		GHz
Output Capacitance	Cob	V _{CB} =3V, f=1MHz		1.0	1.5	pF
Reverse Transfer Capacitance	Cre	V _{CB} =3V, f=1MHz	W. W.	0.7		pF
Forward Transfer Gain	S21e ²	V _{CE} =3V, I _C =7m <mark>A, f=1GHz</mark>	8	10		dB
Noise Figure	NF	V _{CE} =3V, I _C =7mA, f=1GHz		1.4	2.5	dB

Marking: NA

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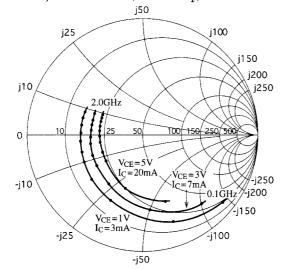




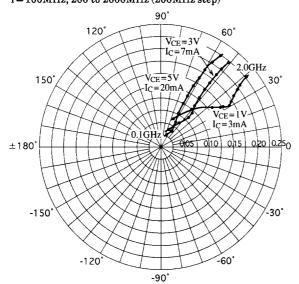
S Parameters

S11e

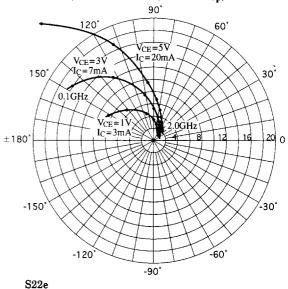
f = 100MHz, 200 to 2000MHz (200MHz step)



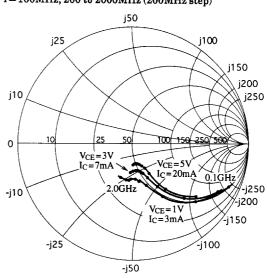
S12e f=100MHz, 200 to 2000MHz (200MHz step)



S21e $f\!=\!100MHz, 200~to~2000MHz~(200MHz~step)$



f=100MHz, 200 to 2000MHz (200MHz step)



2SC5375

S parameters (Common emitter)

 $V_{CE}=1V$, $I_{C}=3mA$, $Z_{O}=50\Omega$

Freq (MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
100	0.875	-40.1	8.529	152.1	0.062	67.4	0.905	-24.3
200	0.782	-70.7	6.673	131.8	0.101	51.6	0.745	-42.0
400	0.621	-115.9	4.733	104.7	0.135	37.2	0.524	-59.1
600	0.576	-138.2	3.353	90.2	0.143	33.3	0.387	-71.5
800	0.547	-155.7	2.686	79.1	0.151	33.0	0.329	-79.4
1000	0.542	-165.4	2.165	70.4	0.165	31.2	0.330	-80.5
1200	0.534	-174.7	1.873	62.4	0.173	33.0	0.310	-86.0
1400	0.529	178.3	1.638	55.7	0.184	35.1	0.295	-91.9
1600	0.529	170.8	1.480	49.7	0.194	35.6	0.308	-95.7
1800	0.533	165.4	1.321	43.4	0.208	36.8	0.312	-101.6
2000	0.532	159.3	1.215	38.3	0.227	38.6	0.304	-109.1

V_{CE} =3V, I_{C} =7mA, Z_{O} =50 Ω

Freq (MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠ S ₂₂
100	0.777	-48.9	16.116	146.5	0.040	65.9	0.852	-29.0
200	0.643	-84.8	12.223	124.2	0.061	52.9	0.646	-46.3
400	0.505	-126.1	7.484	101.5	0.083	46.6	0.428	-58.8
600	0.473	-146.2	5.198	89.7	0.096	48.3	0.317	-65.6
800	0.454	-160.6	3.984	80.7	0.112	49.9	0.273	-70.2
1000	0.446	-170.4	3.275	73.6	0.129	51.4	0.248	-74.1
1200	0.449	-177.6	2.738	66.9	0.147	52.0	0.239	-76.3
1400	0.445	175.5	2.391	61.2	0.165	52.4	0.229	-79.6
1600	0.443	168.9	2.135	55.9	0.184	52.4	0.225	-84.6
1800	0.439	164.1	1.944	50.5	0.203	51.5	0.227	-90.0
2000	0.443	157.7	1.760	45.7	0.222	50.4	0.240	-93.0

$V_{CE}=5V, I_{C}=20mA, Z_{O}=50\Omega$

Freq (MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠ S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠ S ₂₂
100	0.595	-70.3	26.610	134.3	0.028	62.1	0.724	-39.3
200	0.480	-107.7	17.090	113.5	0.041	56.3	0.482	-54.3
400	0.406	-143.8	9.432	95.7	0.060	58.8	0.296	-61.9
600	0.393	-160.3	6.459	86.2	0.079	61.8	0.227	-64.4
800	0.388	-171.0	4.909	79.0	0.100	62.8	0.200	-67.5
1000	0.387	-178.6	3.989	73.3	0.121	62.8	0.188	-70.3
1200	0.390	175.1	3.356	67.3	0.142	62.0	0.182	-72.4
1400	0.385	169.8	2.918	62.1	0.163	61.0	0.176	-75.0
1600	0.386	163.9	2.588	57.7	0.184	59.9	0.173	-80.1
1800	0.388	159.8	2.322	52.8	0.205	57.9	0.177	-85.8
2000	0.394	154.7	2.117	48.5	0.226	56.0	0.185	-89.4

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